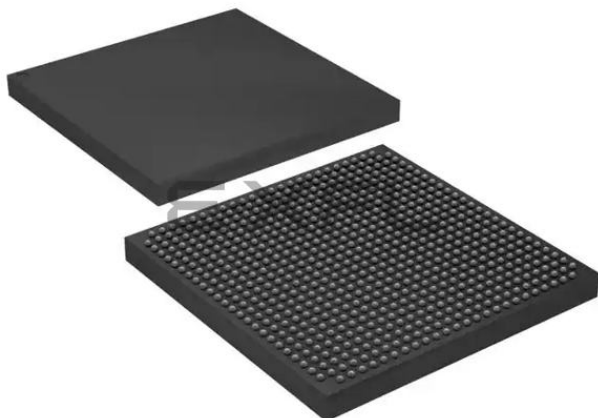




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Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

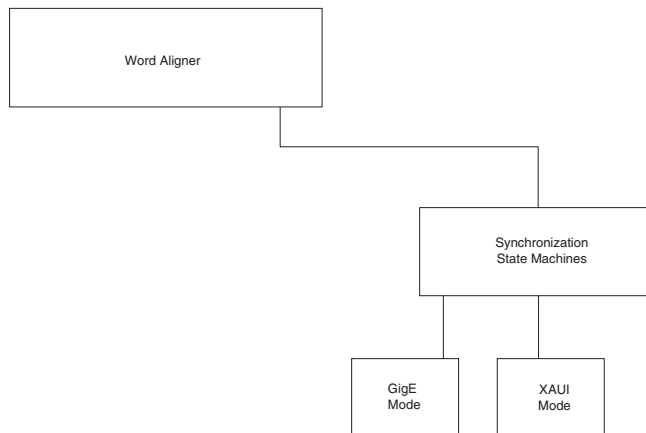
The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Obsolete
Number of LABs/CLBs	1057
Number of Logic Elements/Cells	10570
Total RAM Bits	920448
Number of I/O	362
Number of Gates	-
Voltage - Supply	1.425V ~ 1.575V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	672-BBGA
Supplier Device Package	672-FBGA (27x27)
Purchase URL	https://www.e-xfl.com/product-detail/intel/ep1sgx10cf672c5

- Pattern detector and word aligner supports programmable patterns
 - 8B/10B encoder/decoder performs 8- to 10-bit encoding and 10- to 8-bit decoding
 - Rate matcher compliant with IEEE 802.3-2002 for GigE mode and with IEEE 802.3ae for XAUI mode
 - Channel bonding compliant with IEEE 802.3ae (for XAUI mode only)
 - Device can bypass some transceiver block features if necessary
- FPGA features are as follows:
- 10,570 to 41,250 logic elements (LEs); see [Table 1–1](#)
 - Up to 3,423,744 RAM bits (427,968 bytes) available without reducing logic resources
 - TriMatrix™ memory consisting of three RAM block sizes to implement true dual-port memory and first-in-out (FIFO) buffers
 - Up to 16 global clock networks with up to 22 regional clock networks per device region
 - High-speed DSP blocks provide dedicated implementation of multipliers (faster than 300 MHz), multiply-accumulate functions, and finite impulse response (FIR) filters
 - Up to eight general usage phase-locked loops (four enhanced PLLs and four fast PLLs) per device provide spread spectrum, programmable bandwidth, clock switchover, real-time PLL reconfiguration, and advanced multiplication and phase shifting
 - Support for numerous single-ended and differential I/O standards
 - High-speed source-synchronous differential I/O support on up to 45 channels for 1-Gbps performance
 - Support for source-synchronous bus standards, including 10-Gigabit Ethernet XSBI, Parallel RapidIO, UTOPIA IV, Network Packet Streaming Interface (NPSI), HyperTransport™ technology, SPI-4 Phase 2 (POS-PHY Level 4), and SFI-4
 - Support for high-speed external memory, including zero bus turnaround (ZBT) SRAM, quad data rate (QDR and QDRII) SRAM, double data rate (DDR) SDRAM, DDR fast cycle RAM (FCRAM), and single data rate (SDR) SDRAM
 - Support for multiple intellectual property megafunctions from Altera® MegaCore® functions and Altera Megafunction Partners Program (AMPPSM) megafunctions
 - Support for remote configuration updates
 - Dynamic phase alignment on LVDS receiver channels

Figure 2–18. Word Aligner in XAUI Mode



In the XAUI and GIGE modes, the word alignment is controlled by a state machine that adheres to the IEEE 802.3ae standard for XAUI and the IEEE 802.3 standard for GIGE. The alignment pattern is predefined to be a $/K28.5/$ code group.

The XAUI mode is available only for the XAUI protocol, and the GIGE mode is available only for the GIGE protocol.

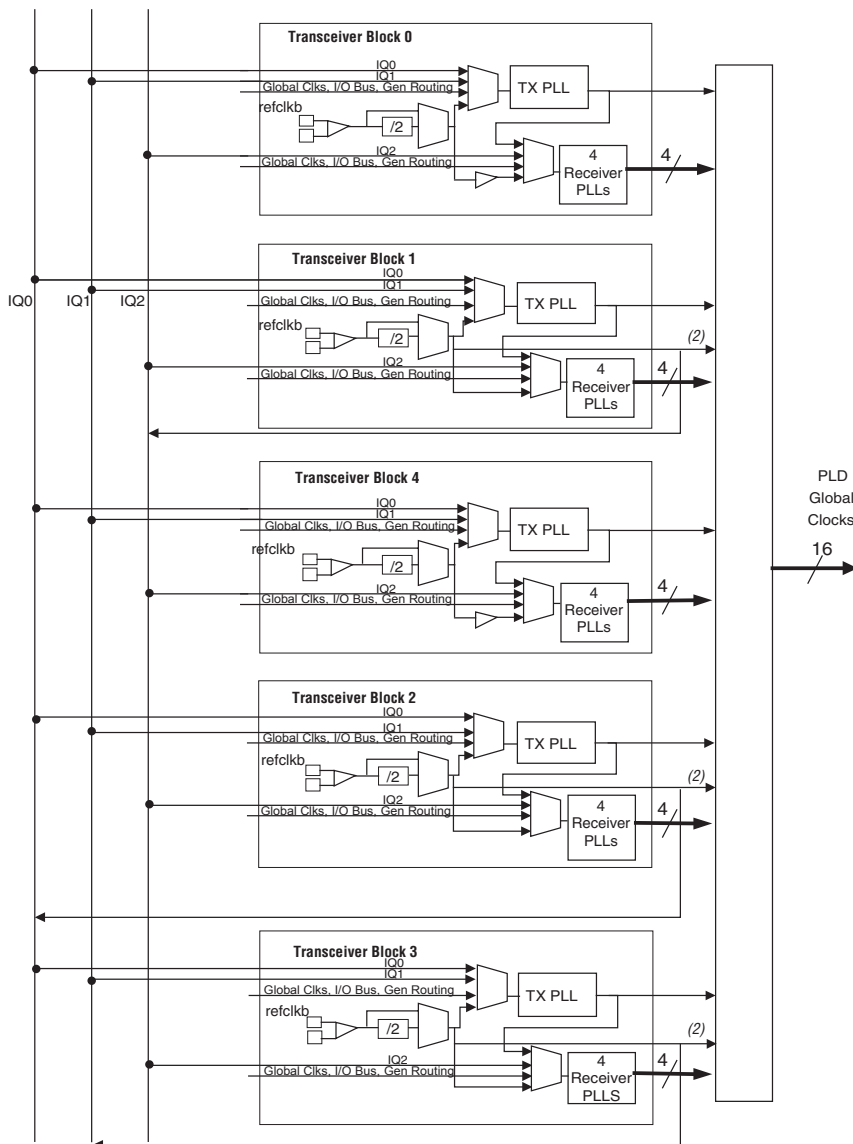
Channel Aligner

The channel aligner is available only in XAUI mode and bonds all four channels within a transceiver. The channel aligner adheres to the IEEE 802.3ae, clause 48 specification for channel bonding.

The channel aligner is a 16-word deep FIFO buffer with a state machine overlooking the channel bonding process. The state machine looks for an $/A/$ ($/K28.3/$) in each channel and aligns all the $/A/s$ in the transceiver. When four columns of $/A/$ (denoted by $//A//$) are detected, the `rx_channelalign` port goes high, signifying that all the channels in the transceiver have been bonded. The reception of four consecutive misaligned $/A/s$ restarts the channel alignment sequence and de-asserts `rx_channelalign`.

Figure 2–19 shows misaligned channels before the channel aligner and the channel alignment after the channel aligner.

Figure 2–27. EP1SGX40G Device Inter-Transceiver & Global Clock Connections *Note (1)*



Notes to Figure 2–27:

- (1) IQ lines are inter-transceiver block lines.
- (2) If the /2 pre-divider is used, the path to drive the PLD logic array, local, or global clocks is not allowed.
- (3) There are four receiver PLLs in each transceiver block.

Introduction

Expansion in the telecommunications market and growth in Internet use requires systems to move more data faster than ever. To meet this demand, rely on solutions such as differential signaling and emerging high-speed interface standards including RapidIO, POS-PHY 4, SFI-4, or XSBI.

These new protocols support differential data rates up to 1 Gbps and higher. At these high data rates, it becomes more challenging to manage the skew between the clock and data signals. One solution to this challenge is to use CDR to eliminate skew between data channels and clock signals. Another potential solution, DPA, is beginning to be incorporated into some of these protocols.

The source-synchronous high-speed interface in Stratix GX devices is a dedicated circuit embedded into the PLD allowing for high-speed communications. The *High-Speed Source-Synchronous Differential I/O Interfaces in Stratix GX Devices* chapter of the *Stratix GX Device Handbook, Volume 2* provides information on the high-speed I/O standard features and functions of the Stratix GX device.

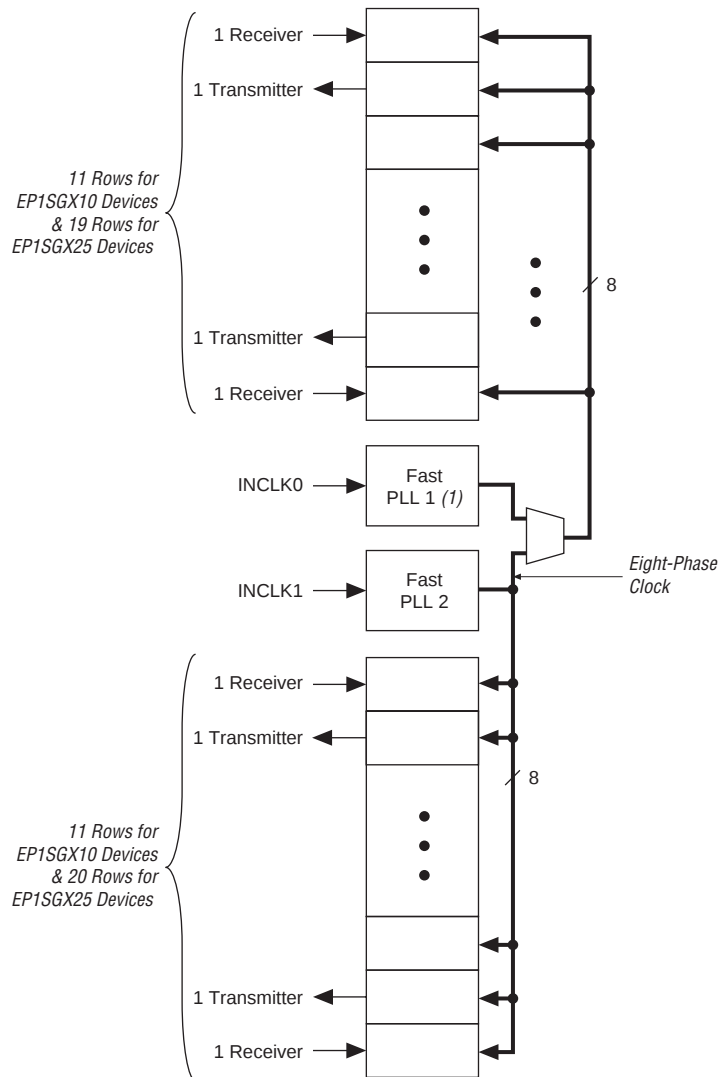
Stratix GX I/O Banks

Stratix GX devices contain 17 I/O banks. I/O banks one and two support high-speed LVDS, LVPECL, and 3.3-V PCML inputs and outputs. These two banks also incorporate an embedded dynamic phase aligner within the source-synchronous interface (see [Figure 3-8 on page 3-10](#)). The dynamic phase aligner corrects for the phase difference between the clock and data lines caused by skew. The dynamic phase aligner operates automatically and continuously without requiring a fixed training pattern, and allows the source-synchronous circuitry to capture data correctly regardless of the channel-to-clock skew.

Principles of SERDES Operation

Stratix GX devices support source-synchronous differential signaling up to 1 Gbps in DPA mode, and up to 840 Mbps in non-DPA mode. Serial data is transmitted and received along with a low-frequency clock. The PLL can multiply the incoming low-frequency clock by a factor of 1 to 10. The SERDES factor J can be 8 or 10 for the DPA mode, or 4, 7, 8, or 10 for all other modes. The SERDES factor does not have to equal the clock

Figure 3–6. PLL & Channel Layout in EP1SGX10 & EP1SGX25 Devices *Notes (1), (2)*



Notes to Figure 3–6:

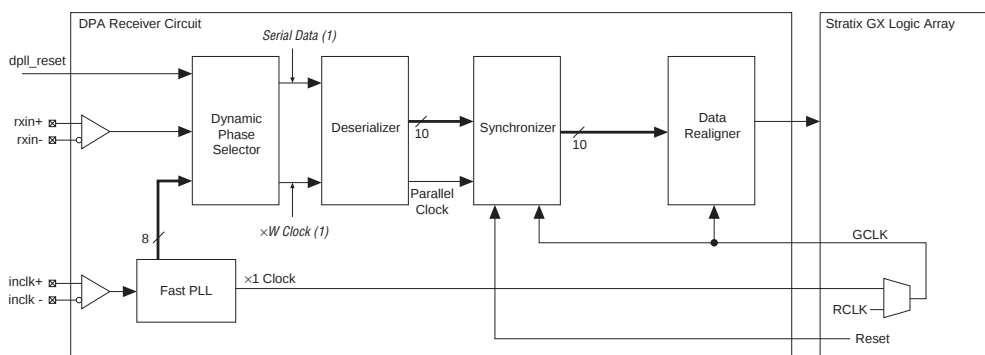
- (1) Fast PLL 1 in EP1SGX10 devices does not support DPA.
- (2) Not all eight phases are used by the receiver channel or transmitter channel in non-DPA mode.

DPA Operation

The DPA receiver circuitry contains the dynamic phase selector, the deserializer, the synchronizer, and the data realigner (see [Figure 3–8](#)). This section describes the DPA operation, synchronization and data realignment. In the SERDES with DPA mode, the source clock is fed to the fast PLL through the dedicated clock input pins. This clock is multiplied by the multiplication value W to match the serial data rate.

For information on the deserializer, see “[Principles of SERDES Operation](#)” on page 3–1.

Figure 3–8. DPA Receiver Circuit

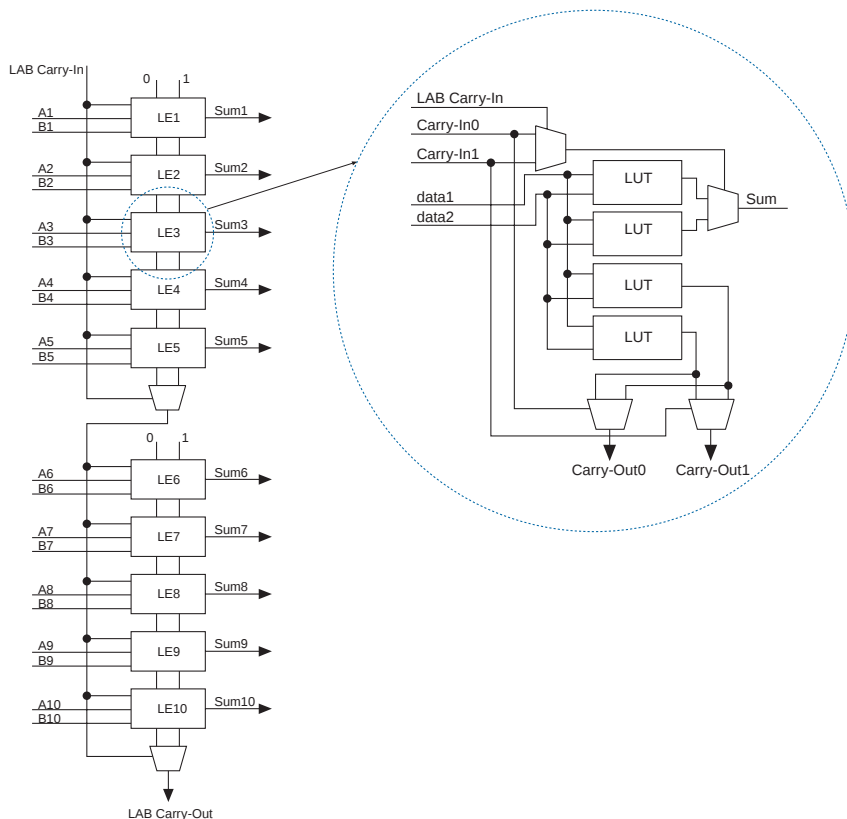


Note to Figure 3–8:

(1) These are phase-matched and retimed high-speed clocks and data.

The dynamic phase selector matches the phase of the high-speed clock and data before sending them to the deserializer.

The fast PLL supplies eight phases of the same clock (each a separate tap from a four-stage differential VCO) to all the differential channels associated with the selected fast PLL. The DPA circuitry inside each channel locks to a phase closest to the serial data’s phase and sends the retimed data and the selected clock to the deserializer. The DPA circuitry automatically performs this operation and is not something you select. Each channel’s DPA circuit can independently choose a different clock phase. The data phase detection and the clock phase selection process is automatic and continuous. The eight phases of the clock give the DPA circuit a granularity of one eighth of the unit interval (UI) or 125 ps at 1 Gbps. [Figure 3–9](#) illustrates the clocks generated by the fast PLL circuitry and their relationship to a data stream.

Figure 4–7. Carry Select Chain

Clear & Preset Logic Control

LAB-wide signals control the logic for the register's clear and preset signals. The LE directly supports an asynchronous clear and preset function. The register preset is achieved through the asynchronous load of a logic high. The direct asynchronous preset does not require a NOT-gate push-back technique. Stratix GX devices support simultaneous preset/ asynchronous load, and clear signals. An asynchronous clear signal takes precedence if both signals are asserted simultaneously. Each LAB supports up to two clears and one preset signal.

In addition to the clear and preset ports, Stratix GX devices provide a chip-wide reset pin (DEV_CLRn) that resets all registers in the device. An option set before compilation in the Quartus II software controls this pin. This chip-wide reset overrides all other control signals.

or regional clock. In contrast, a circuit using asynchronous RAM must generate the RAM `WREN` signal while ensuring its data and address signals meet setup and hold time specifications relative to the `WREN` signal. The output registers can be bypassed. Flow-through reading is possible in the simple dual-port mode of M512 and M4K RAM blocks by clocking the read enable and read address registers on the negative clock edge and bypassing the output registers.

Two single-port memory blocks can be implemented in a single M4K block as long as each of the two independent block sizes is equal to or less than half of the M4K block size.

The Quartus II software automatically implements larger memory by combining multiple TriMatrix memory blocks. For example, two 256×16 -bit RAM blocks can be combined to form a 256×32 -bit RAM block. Memory performance does not degrade for memory blocks using the maximum number of words available in one memory block. Logical memory blocks using less than the maximum number of words use physical blocks in parallel, eliminating any external control logic that would increase delays. To create a larger high-speed memory block, the Quartus II software automatically combines memory blocks with LE control logic.

Parity Bit Support

The memory blocks support a parity bit for each byte. The parity bit, along with internal LE logic, can implement parity checking for error detection to ensure data integrity. You can also use parity-size data words to store user-specified control bits. In the M4K and M-RAM blocks, byte enables are also available for data input masking during write operations.

Shift Register Support

You can configure embedded memory blocks to implement shift registers for DSP applications such as pseudo-random number generators, multi-channel filtering, auto-correlation, and cross-correlation functions. These and other DSP applications require local data storage, traditionally implemented with standard flip-flops, which can quickly consume many logic cells and routing resources for large shift registers. A more efficient alternative is to use embedded memory as a shift register block, which saves logic cell and routing resources and provides a more efficient implementation with the dedicated circuitry.

The size of a $w \times m \times n$ shift register is determined by the input data width (w), the length of the taps (m), and the number of taps (n). The size of a $w \times m \times n$ shift register must be less than or equal to the maximum number of memory bits in the respective block: 576 bits for the M512

M-RAM Block

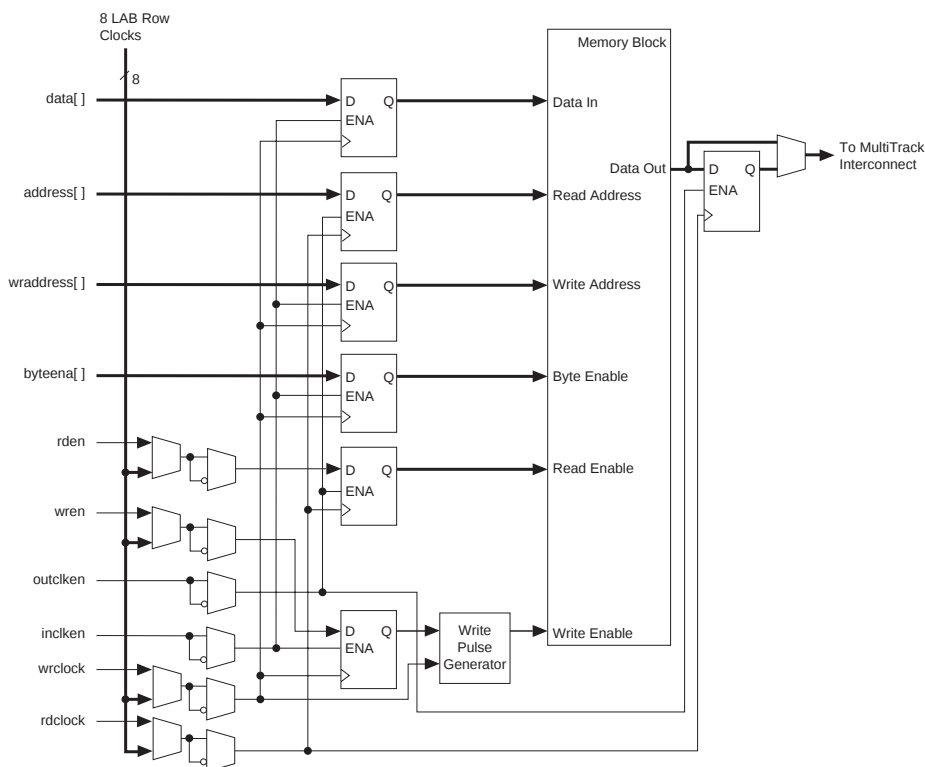
The largest TriMatrix memory block, the M-RAM block, is useful for applications where a large volume of data must be stored on-chip. Each block contains 589,824 RAM bits (including parity bits). The M-RAM block can be configured in the following modes:

- True dual-port RAM
- Simple dual-port RAM
- Single-port RAM
- FIFO RAM

You cannot use an initialization file to initialize the contents of a M-RAM block. All M-RAM block contents power up to an undefined value. Only synchronous operation is supported in the M-RAM block, so all inputs are registered. Output registers can be bypassed. The memory address and output width can be configured as 64K × 8 (or 64K × 9 bits), 32K × 16 (or 32K × 18 bits), 16K × 32 (or 16K × 36 bits), 8K × 64 (or 8K × 72 bits), and 4K × 128 (or 4K × 144 bits). The 4K × 128 configuration is unavailable in true dual-port mode because there are a total of 144 data output drivers in the block. Mixed-width configurations are also possible, allowing different read and write widths. [Tables 4-7](#) and [4-8](#) summarize the possible M-RAM block configurations:

Table 4-7. M-RAM Block Configurations (Simple Dual-Port)					
Read Port	Write Port				
	64K × 9	32K × 18	16K × 36	8K × 72	4K × 144
64K × 9	✓	✓	✓	✓	
32K × 18	✓	✓	✓	✓	
16K × 36	✓	✓	✓	✓	
8K × 72	✓	✓	✓	✓	
4K × 144					✓

blocks facing to the left, and another 10 possible from the right adjacent LABs for M-RAM blocks facing to the right. For column interfacing, every M-RAM column unit connects to the right and left column lines, allowing each M-RAM column unit to communicate directly with three columns of LABs. [Figures 4–20](#) through [4–22](#) show the interface between the M-RAM block and the logic array.

Figure 4–26. Read/Write Clock Mode in Simple Dual-Port Mode*Note (1)***Note to Figure 4–26:**

(1) All registers shown except the rden register have asynchronous clear ports.

Single-Port Mode

The memory blocks also support single-port mode, used when simultaneous reads and writes are not required. See Figure 4–27. A single block in a memory block can support up to two single-port mode RAM blocks in the M4K RAM blocks if each RAM block is less than or equal to 2K bits in size.

Input Registers

A bank of optional input registers is located at the input of each multiplier and multiplicand inputs to the multiplier. When these registers are configured for parallel data inputs, they are driven by regular routing resources. You can use a clock signal, asynchronous clear signal, and a clock enable signal to independently control each set of A and B inputs for each multiplier in the DSP block. You select these control signals from a set of four different `clock[3..0]`, `aclr[3..0]`, and `ena[3..0]` signals that drive the entire DSP block.

You can also configure the input registers for a shift register application. In this case, the input registers feed the multiplier and drive two dedicated shift output lines: `shiftoutA` and `shiftoutB`. The shift outputs of one multiplier block directly feed the adjacent multiplier block in the same DSP block (or the next DSP block) as shown in [Figure 4-32](#), to form a shift register chain. This chain can terminate in any block, that is, you can create any length of shift register chain up to 224 registers. You can use the input shift registers for FIR filter applications. One set of shift inputs can provide data for a filter, and the other are coefficients that are optionally loaded in serial or parallel. When implementing 9×9 - and 18×18 -bit multipliers, you do not need to implement external shift registers in LAB LEs. You implement all the filter circuitry within the DSP block and its routing resources, saving LE and general routing resources for general logic. External registers are needed for shift register inputs when using 36×36 -bit multipliers.

Table 4–13 shows the summary of input register modes for the DSP block.

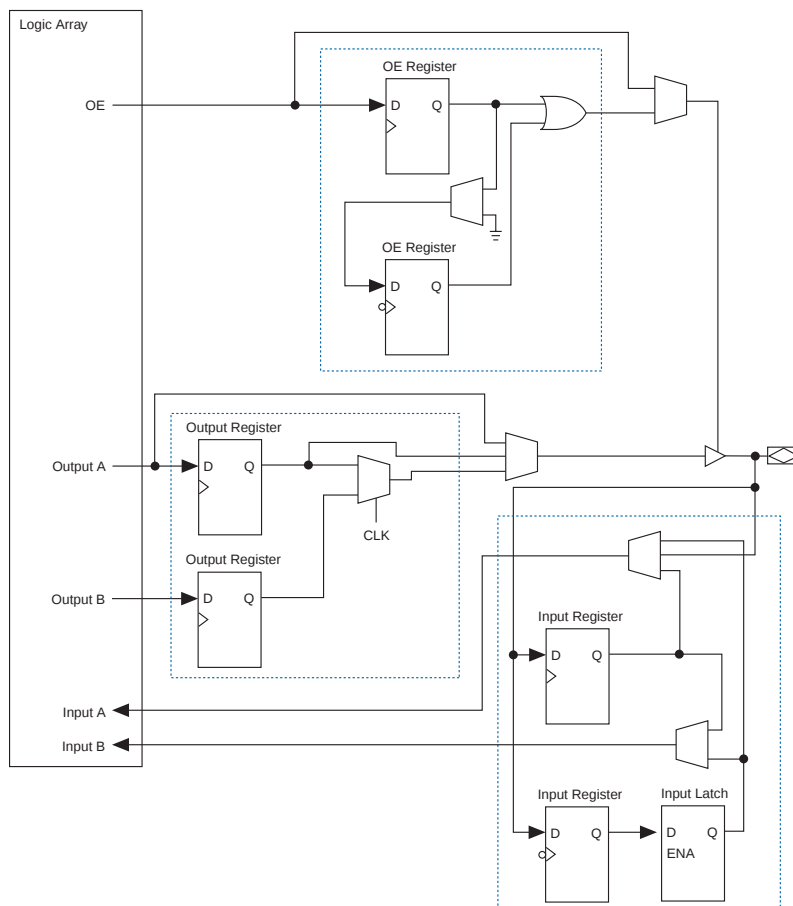
Table 4–13. Input Register Modes			
Register Input Mode	9 × 9	18 × 18	36 × 36
Parallel input	✓	✓	✓
Shift register input	✓	✓	

Multiplier

The multiplier supports 9 × 9-, 18 × 18-, or 36 × 36-bit multiplication. Each DSP block supports eight possible 9 × 9-bit or smaller multipliers. There are four multiplier blocks available for multipliers larger than 9 × 9 bits but smaller than 18 × 18 bits. There is one multiplier block available for multipliers larger than 18 × 18 bits but smaller than or equal to 36 × 36 bits. The ability to have several small multipliers is useful in applications such as video processing. Large multipliers greater than 18 × 18 bits are useful for applications such as the mantissa multiplication of a single-precision floating-point number.

The multiplier operands can be signed or unsigned numbers, where the result is signed if either input is signed as shown in Table 4–14. The `sign_a` and `sign_b` signals provide dynamic control of each operand's representation: a logic 1 indicates the operand is a signed number, a logic 0 indicates the operand is an unsigned number. These sign signals affect all multipliers and adders within a single DSP block and you can register them to match the data path pipeline. The multipliers are full precision (that is, 18 bits for the 18-bit multiply, 36-bits for the 36-bit multiply, and so on), regardless of whether `sign_a` or `sign_b` set the operands as signed or unsigned numbers.

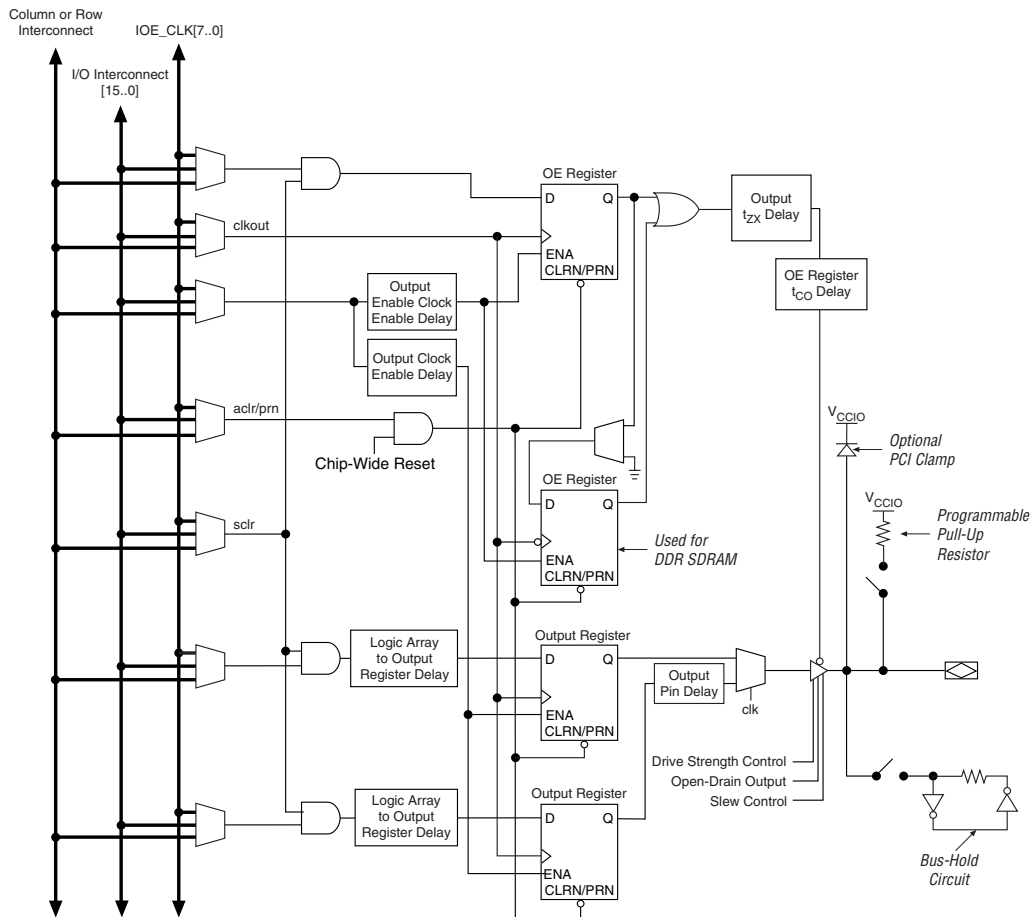
Table 4–14. Multiplier Signed Representation		
Data A	Data B	Result
Unsigned	Unsigned	Unsigned
Unsigned	Signed	Signed
Signed	Unsigned	Signed
Signed	Signed	Signed

Figure 4–58. Stratix GX IOE Structure

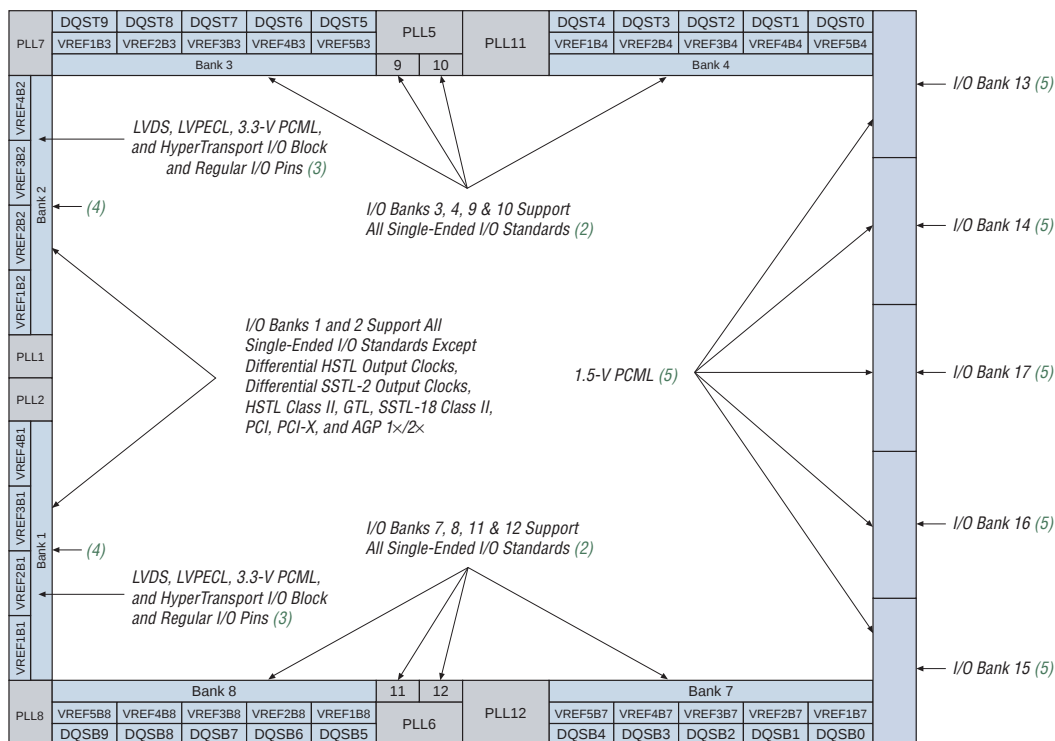
The IOEs are located in I/O blocks around the periphery of the Stratix GX device. There are up to four IOEs per row I/O block and six IOEs per column I/O block. The row I/O blocks drive row, column, or direct link interconnects. The column I/O blocks drive column interconnects.

Figure 4–59 shows how a row I/O block connects to the logic array.

Figure 4–60 shows how a column I/O block connects to the logic array.

Figure 4–66. Stratix GX IOE in DDR Output I/O Configuration *Notes (1), (2)***Notes to Figure 4–66:**

- (1) All input signals to the IOE can be inverted at the IOE.
- (2) The tristate is by default active high. It can, however, be designed to be active low.



Notes to Figure 4-69:

- (1) Figure 4-69 is a top view of the Stratix GX silicon die.
- (2) Banks 9 through 12 are enhanced PLL external clock output banks.
- (3) If the high-speed differential I/O pins are not used for high-speed differential signaling, they can support all of the I/O standards except HSTL class I and II, GTL, SSTL-18 Class II, PCI, PCI-X, and AGP 1×/2×.
- (4) For guidelines for placing single-ended I/O pads next to differential I/O pads, see the *Selectable I/O Standards in Stratix & Stratix GX Devices* chapter in the *Stratix GX Device Handbook, Volume 2*.
- (5) These I/O banks in Stratix GX devices also support the LVDS, LVPECL, and 3.3-V PCML I/O standards on reference clocks and receiver input pins (AC coupled)

Table 6–7. Stratix GX Transceiver Block AC Specification (Part 3 of 7)

Symbol / Description	Conditions	-5 Commercial Speed Grade (1)			-6 Commercial & Industrial Speed Grade (1)			-7 Commercial & Industrial Speed Grade (1)			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
Sinusoidal jitter	f = 42.5 kHz at 1.0625 Gbps			1.5			1.5			1.5	UI
	f = 637 kHz at 1.0625 Gbps			0.1			0.1			0.1	UI
Deterministic jitter	2.125 Gbps			0.33			0.33			0.33	UI
Total jitter	2.125 Gbps			0.62			0.62			0.62	UI
Sinusoidal jitter	f = 85 kHz at 2.125 Gbps			1.5			1.5			1.5	UI
	f = 1,274 kHz at 2.125 Gbps			0.1			0.1			0.1	UI
Serial Rapid I/O Receiver Jitter Tolerance using 8B/10B Encoded CJPAT <i>Note (2)</i>											
Deterministic jitter	1.25 Gbps			0.45			0.45			0.45	UI
Total jitter	1.25 Gbps			0.71			0.71			0.71	UI
Deterministic jitter	2.5 Gbps			0.41			0.41			0.41	UI
Total jitter	2.5 Gbps			0.65			0.65			0.65	UI
Deterministic jitter	3.125 Gbps			0.36			0.36			N/A	UI
Total jitter	3.125 Gbps			0.60			0.60			N/A	UI
SONET Receiver Jitter Tolerance using PRBS23 <i>Note (2)</i>											
Sinusoidal jitter	f = 6 kHz at 2.48832 Gbps			1.5			1.5			1.5	UI
	f = 1 MHz at 2.48832 Gbps			0.15			0.15			0.15	UI
XAUI Receiver Jitter Tolerance using 8B/10B Encoded CJPAT <i>Note (2)</i>											
Deterministic jitter	3.125 Gbps			0.37			0.37			N/A	UI
Total jitter	3.125 Gbps			0.65			0.65			N/A	UI

Table 6–7. Stratix GX Transceiver Block AC Specification (Part 4 of 7)

Symbol / Description	Conditions	-5 Commercial Speed Grade (1)			-6 Commercial & Industrial Speed Grade (1)			-7 Commercial & Industrial Speed Grade (1)			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
Sinusoidal jitter	f = 22.1 kHz at 3.125 Gbps			8.5			8.5			N/A	
	f = 1.875 MHz at 3.125 Gbps			0.1			0.1			N/A	
	f = 20 MHz at 3.125 Gbps			0.1			0.1			N/A	
BER (12)				10 ⁻¹²			10 ⁻¹²			10 ⁻¹²	
Receive latency (4)	Single width	7		32	7		32	7		32	(3)
	Double width	5		19	5		19	5		19	(3)
Channel to channel bit skew tolerance (5), (6)	XAUI mode / inter-quadrant only			40			40			N/A	UI (7)
Run-length	(8)			80			80			80	UI
Receive return loss (differential)	100 MHz to 2.5 Ghz			–10			–10			–10	dB
Receive return loss (common mode)	100 MHz to 2.5 Ghz			–6			–6			–6	dB
Transmitter											
Serial data rate	Commercial / industrial	500		3,187.5	500		3,187.5	500		2,500	Mbps
Parallel transceiver/core interface speed		20		398.4	20		375	20		312.5	MHz
8B/10B Custom Transmitter Jitter using Encoded CRPAT Note (9)											
Deterministic jitter	500 Mbps Pre-emphasis = 1			0.11			0.11			0.11	UI
Total jitter	V _{OD} = 1,400 mV			0.18			0.18			0.18	UI

Table 6–29. 1.5-V HSTL Class I Specifications (Part 2 of 2)

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Units
V_{OH}	High-level output voltage	$I_{OH} = 8 \text{ mA}$ (1)	$V_{CCIO} - 0.4$			V
V_{OL}	Low-level output voltage	$I_{OH} = -8 \text{ mA}$ (1)			0.4	V

Table 6–30. 1.5-V HSTL Class II Specifications

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Units
V_{CCIO}	Output supply voltage		1.4	1.5	1.6	V
V_{REF}	Input reference voltage		0.68	0.75	0.9	V
V_{TT}	Termination voltage		0.7	0.75	0.8	V
$V_{IH} \text{ (DC)}$	DC high-level input voltage		$V_{REF} + 0.1$			V
$V_{IL} \text{ (DC)}$	DC low-level input voltage		-0.3		$V_{REF} - 0.1$	V
$V_{IH} \text{ (AC)}$	AC high-level input voltage		$V_{REF} + 0.2$			V
$V_{IL} \text{ (AC)}$	AC low-level input voltage				$V_{REF} - 0.2$	V
V_{OH}	High-level output voltage	$I_{OH} = 16 \text{ mA}$ (1)	$V_{CCIO} - 0.4$			V
V_{OL}	Low-level output voltage	$I_{OH} = -16 \text{ mA}$ (1)			0.4	V

Table 6–31. 1.5-V Differential HSTL Specifications

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Units
V_{CCIO}	I/O supply voltage		1.4	1.5	1.6	V
$V_{DIF} \text{ (DC)}$	DC input differential voltage		0.2			V
$V_{CM} \text{ (DC)}$	DC common mode input voltage		0.68		0.9	V
$V_{DIF} \text{ (AC)}$	AC differential input voltage		0.4			V

Table 6–32. CTT I/O Specifications (Part 1 of 2)

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Units
V_{CCIO}	Output supply voltage		3.0	3.3	3.6	V
V_{TT}/V_{REF}	Termination and input reference voltage		1.35	1.5	1.65	V
V_{IH}	High-level input voltage		$V_{REF} + 0.2$			V
V_{IL}	Low-level input voltage				$V_{REF} - 0.2$	V